

Transport properties of hydrogen-passivated graphene systems

A. Mreńca and B. Szafran

*AGH University of Science and Technology,
Faculty of Physics and Applied Computer Science,
al. Mickiewicza 30, 30-059 Kraków, Poland*

The transport properties of graphene nanoribbons as described by the p_z tight binding theory and its Dirac low-energy approximation predict metallic dispersion relation for zig-zag and armchair nanoribbons with $3n+2$ atoms across the channel. For these ribbons formation of perfectly conducting channels is predicted by the theory [1]. In fact, the transport experiments resolve a finite transport gap [2, 3] near the neutrality point for all types of nanoribbons. The finite band gaps originate from quantum confinement, edge disorder effects, and/or passivation [4, 5, 6] of the dangling bonds at the edges of the ribbon. Formation of energy gaps is reported by the ab-initio calculations [5, 6] for the dispersion relation of the nanoribbons.

In this paper we study the transport properties of nanoribbons with hydrogen-passivated edges and discuss the effects of the passivation for the systems based on nanoribbons as electron scatterers. We use the tight binding approach using three p/d orbitals per atom [6] and develop a version of quantum transmitting boundary method [7] to study the transport with the Landauer approach. We confront the results obtained for the passivation model against the results of a single- p_z tight binding model. Our study involves graphene nanoribbons perturbed by external potentials and quantum point contact of various geometries.

- [1] K. Wakabayashi, Y. Takane, M. Yamamoto, and M. Sigrist, *Carbon* **47**, 124 (2009); J. Wurm, M. Wimmer, and K. Richter, *Phys. Rev. B* **85**, 245418 (2012).
- [2] M.Y. Han, B. Özyilmaz, Y. Zhang, P. Kim, *Phys. Rev. Lett.* **98**, 206805 (2007).
- [3] Z. Chen, Y.-M. Lin, M.J. Rooks, P. Avouris, *Phys. E*, **40**, 228 (2007).
- [4] L. Yang, C.-H. Park, Y.-W. Son, M.L. Cohen, S.G. Louie, *Phys. Rev. Lett.* **99**, 186801 (2007).
- [5] Y.-W. Son, M.L. Cohen, S.G. Louie, *Phys. Rev. Lett.* **97**, 216803 (2006).
- [6] T.B. Boykin, M. Luisier, G. Klimeck, X. Jiang, N. Kharche, Y. Zhou, S.K. Nayak *J. Appl. Phys.* **109**, 104304 (2011).
- [7] K. Kolasiński, B. Szafran, *Phys. Rev. B* **89**, 165306 (2014).